

## SANYO Semiconductors DATA SHEET

An ON Semiconductor Company

### **Monolithic Digital IC**

# LB1980JH — 3-Phase Brushless Motor Driver

#### Overview

The LB1980JH is a 3-phase brushless motor driver that is particularly appropriate for automotive.

#### **Functions**

- 3-phase full-wave drive
- Built-in torque ripple correction circuit (variable correction ratio)
- Current limiter circuit
- Upper and lower side output stage over-saturation prevention circuit that does not require external capacitors.
- FG amplifier
- Thermal shutdown circuit

#### **Specifications**

#### **Absolute Maximum Ratings** at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage V <sub>CC</sub> max			7	٧
	V <sub>S</sub> max		24	V
Maximum output current	I <sub>O</sub> max		1.3	Α
Allowable power dissipation	Pd max	Mounted on a board *	1.81	W
		Independent IC	0.77	W
Operating temperature	Topr		-30 to 85	°C
Storage temperature	Tstg		-55 to +150	°C

<sup>\*</sup> Mounted on a 76.1mm×114.3mm×1.6mm, glass epoxy printed circuit board.

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## LB1980JH

## Allowable Operating Ranges at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage	٧s		5 to 22	V
	VCC		4.5 to 5.5	V
Hall input amplitude	V <sub>HALL</sub>	Between the hall inputs	±30 to ±80	mVo-p
GSENSE pin input range	VGSENSE	With respect to the control system ground	-0.20 to +0.20	V

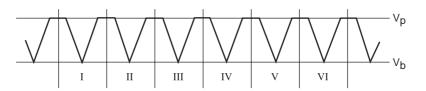
## **Electrical Characteristics** at Ta = 25 °C, $V_{CC} = 5V$ , $V_S = 15V$

Parameter	Symbol	Conditions	Ratings			Unit
Falanielei	Symbol	Conditions	min typ		max	Offit
V <sub>CC</sub> supply current	lcc	R <sub>L</sub> =∞, V <sub>CTL</sub> =0V, V <sub>LIM</sub> =0V (Quiescent)		12	18	mA
Outputs						
Output saturation voltage	VO sat1	I <sub>O</sub> =500mA, Rf=0.5Ω, Sink+Source V <sub>CTL</sub> =V <sub>LIM</sub> =5V(With saturation prevention)		2.1	2.6	V
	VO sat2	I <sub>O</sub> =1.0mA, Rf=0.5Ω, Sink+Source V <sub>CTL</sub> =V <sub>LIM</sub> =5V(With saturation prevention)		2.6	3.5	٧
Output leakage current	I <sub>O</sub> leak				1.0	mA
FR						
FR pin input threshold voltage	V <sub>FSR</sub>		2.25	2.50	2.75	V
FR pin input bias current	I <sub>B</sub> (FSR)		-5.0			mA
Control				•	'	
CTLREF pin voltage	VCREF		2.05	2.15	2.25	V
CTLREF pin input range	VCREFIN		1.50		3.50	V
CTL pin input bias current	I <sub>B</sub> (CTL)	With V <sub>CTL</sub> =5V and the CTLREF pin open			4.0	μΑ
CTL pin control start voltage	V <sub>CTL</sub> (ST)	With Rf=0.5Ω, V <sub>LIM</sub> =5V, I <sub>O</sub> ≥10mA, Hall input logic fixed (U, V, W=H, H, L)	2.00	2.15	2.30	V
CTL pin control Gm	Gm(CTL)	With Rf=0.5Ω, ΔI <sub>O</sub> =200mA, Hall input logic fixed (U, V, W=H, H, L)	0.46	0.58	0.70	A/V
Current Limiter				•	'	
LIM current limit offset voltage	Voff(LIM)	With Rf=0.5 $\Omega$ , V <sub>CTL</sub> =5V, I <sub>O</sub> $\ge$ 10mA, Hall input logic fixed (U, V, W=H, H, L)	140	200	260	mV
LIM pin input bias current	I <sub>B</sub> (LIM)	With V <sub>CTL</sub> =5V and the V <sub>CREF</sub> pin open	-2.5			μА
LIM pin current control level	ILIM	With Rf=0.5Ω, V <sub>CTL</sub> =5V, V <sub>LIM</sub> =2.06V Hall input logic fixed (U, V, W=H, H, L)	830	900	970	mA
Hall Amplifier			•			
Hall amplifier input offset voltage	Voff(HALL)		-6		+6	mA
Hall amplifier input bias current	I <sub>B</sub> (HALL)			1.0	3.0	μΑ
Hall amplifier common-mode input voltage range	V <sub>CM</sub> (HALL)			1.3	3.3	V
TRC			<u> </u>	L	i	
Torque ripple correction ratio	TRC	For the high and low peaks in the Rf waveform when $I_O=200$ mA. (Rf=0.5 $\Omega$ , with the ADJ pin open) *1		9		%
ADJ pin voltage	V <sub>ADJ</sub>	(NI=0.052, With the ADO pill open)	2.37	2.50	2.63	V
FG Amplifier	ADS					
FG amplifier input offset voltage	Voff(FG)		-8		+8	mV
FG amplifier input bias current	I <sub>B</sub> (FG)		-100			nA
FG amplifier output saturation	V <sub>O</sub> sat (FG)	Sink side, for the load provided by the internal		+	0.5	V
voltage	.0 -3. (. 0)	pull-up resistor			0.0	•
FG amplifier voltage gain	V <sub>G</sub> (FG)	For the open loop state with f=10kHz	41.5	44.5	47.5	dB
FG amplifier common-mode	V <sub>GM</sub> (FG)		0.5		4.0	V
input voltage						
Saturation		<u>,                                      </u>	1			
Saturation prevention circuit lower side voltage setting	VO sat(DET)	The voltages between each OUT and Rf pair when I <sub>O</sub> =10mA, Rf=0.5Ω, and VCTL=VLIM=5V	0.175	0.25	0.325	V
TSD		· L		<u> </u>		
TSD operating temperature	TSD	Design target value *2		180		°C
100 operating temperature						

Notes: \*1. The torque ripple correction ratio is determined as follows from the Rf voltage waveform.

<sup>\*2.</sup> Parameters that are indicated as design target values in the conditions column are not tested.

## **LB1980JH**



For each Hall logic setting

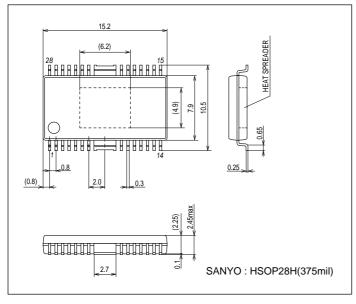
Ground level

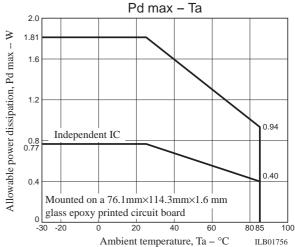
Correction ratio = 
$$\frac{25(V_p - V_b)}{V_p - V_b} 1005(\%)$$

## **Package Dimensions**

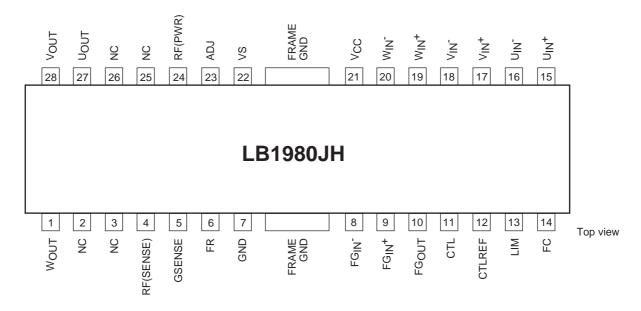
unit : mm (typ)

3233B

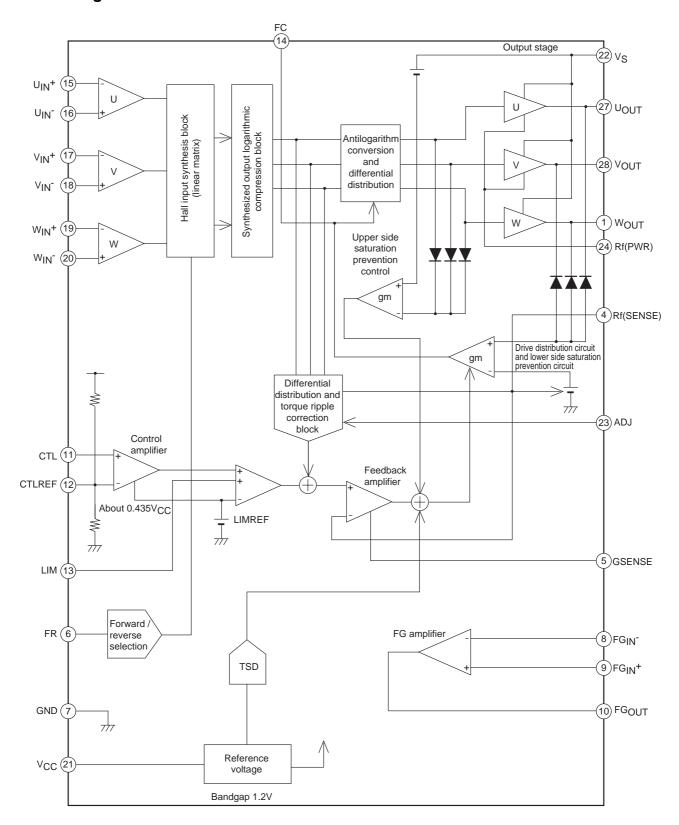




## **Pin Assignment**



## **Block Diagram**



## LB1980JH

## **Pin Function**

Pin No.	Pin Name	Function	Equivalent circuit
27	U <sub>OUT</sub>	U phase output, Spark killer diodes are built-in.	1
28	VOUT	V phase output, Spark killer diodes are built-in.	
1	Wout	W phase output, Spark killer diodes are built-in.	20 Mag
			22) VCC
4	Rf	Output current detection. The control block current limiter	27 S 150μA 28 Lower side saturation
	(SENSE)	operates using the resistor Rf connected between these	(28) Lower side saturation
5	Rf	pins and ground. Also, the lower side saturation	prevention circuit input block
	(PWR)	prevention circuit and the torque ripple correction circuit	VCC 200Ω
		operate based on the voltages across this resistor. It is	
		especially important to note that, since the saturation	
		prevention level is set using this voltage, the lower side	200Ω (4)—\\\\
		saturation prevention circuit will become less effective in the high current region if the value of Rf is lowered	(4)—(W)—(Rf (SENSE)
		excessively. Also, the PWR and SENSE pins must be	Rf (PWR)
		connected together.	<i>'''</i>
22	٧s	Output block power supply	
5	GSENSE	Ground sensing. The influence of the common ground	
3	GOLINOE	impedance on Rf can be excluded by connecting this pin	
		to nearest ground for the Rf resistor side of the motor	
		ground wiring that includes Rf. (This pin must not be left	
		open.)	
6	FR	Forward / reverse selection. The voltage applied to this	
		pin selects the motor direction (forward or reverse).	Voc. Voc.
		(Vth=2.5V at V <sub>CC</sub> =5V (typical))	VCC
23	ADJ	Used for external adjustment of the torque ripple	
	7.20	correction ratio. Apply a voltage externally with a	200μΑ
		low-impedance circuit to the ADJ pin to adjust the	$_{\text{FR}}$ $_{\text{ADJ}}$ $\stackrel{>}{>}$ $_{\text{10k}\Omega}$ $\stackrel{>}{\downarrow}$ $\stackrel{>}{>}$
		correction ratio. The correction ratio falls as the applied	© · · · · · · · · · · · · · · · · · · ·
		voltage is increased, and increases as the applied voltage	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$
		decreases. The torque ripple correction ratio can be	$\frac{1}{m}$ $\frac{10k\Omega}{m}$ $\frac{10k\Omega}{m}$
		modified by factors in the range 0 to 2 times the ratio that	<b>↑</b>
		applies when his pin is left open. (The pin voltage is set to	मा भागा भागा भागा भागा भागा भागा भागा भा
		about $V_{CC}$ / 2 internally, and the input impedance is about	
		5kΩ.)	
7	GND	Ground for all circuits other than the output transistors.	
		The lowest potential of the output transistors is that of the	
0	FC -	Rf pin.	
8	FG <sub>IN</sub> ⁻	Input used when the FG amplifier is used as an inverting input. A feedback resistor must be connected between	VCC*
		FGOUT and this pin.	
		. 5001 and the pin	5μΑ 🔗
			Ţ
9	FG <sub>IN</sub> +	Non-inverting input used when the FG amplifier is used as	FGIN(-) FGIN(+)
		a differential input amplifier. No bias is applied internally.	$9 \bigvee_{300\Omega} - \bigvee_{300\Omega} - 8$
			\$ 00032 <b>\$</b>
			<i>#</i>
10	FGOUT	FG amplifier output. There is an internal resistive load.	Vcc4 AVcc 4Vcc
			Vcc tvcc
			$\geqslant \geqslant_{2k\Omega}$
			FGOUT [1]
			$\begin{array}{c c} & & & & \\ \hline & \\ \hline & & \\ \hline & \\ \hline & \\ \hline & & \\ \hline & \\$
14	FC	Speed control loop frequency characteristics correction.	
			··· // // /// /// ///

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Pin No.	Pin Name	Function	Equivalent circuit
11	CTL	Speed control input. The control implemented is fixed current drive controlled by current feedback from Rf. Gm=0.58 / V (typical) when Rf=0.5W	VCC ↓VCC VCC↓ ≥10kΩ 200±4
12	CTLREF	Control reference voltage. While this pin is set to about 0.43×V <sub>CC</sub> internally, this voltage can be modified by applying a voltage from a low-impedance circuit. (The input impedance is about 4.3kΩ).	10 - ΛΛ - 200Ω
13	LIM	Current limiter function control. The output current can be varied linearly by applying a voltage to this pin. The slope is $0.5A / V$ (typical) when Rf= $0.5\Omega$ .	100µA
15	U <sub>IN</sub> +	U phase Hall element inputs.	(+) input , (-) input
16	U <sub>IN</sub> -	Logic high is defined as states where IN <sup>+</sup> >IN⁻.	
17	V <sub>IN</sub> +	V phase Hall element inputs.	(9)
18	V <sub>IN</sub> -	Logic high is defined as states where IN <sup>+</sup> >IN <sup>-</sup> .	100μA 20032 †
19	$W_{IN}^+$	W phase Hall element inputs.	Y I
20	$W_{IN}^-$	Logic high is defined as states where IN <sup>+</sup> >IN⁻.	<del>///</del>
21	VCC	Power supply for all internal blocks other than the output block. This voltage must be stabilized so that noise and ripple do not enter the IC.	

#### **Truth Table and Control Functions**

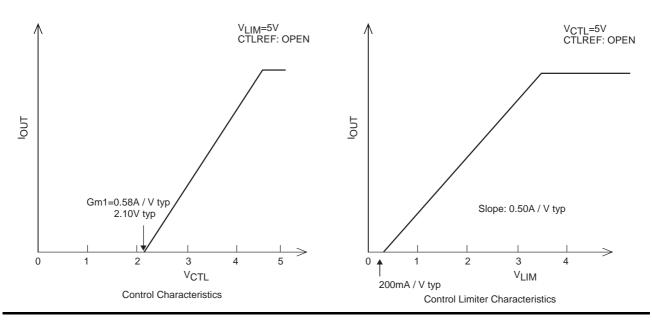
	Course Cink	Hall input			
	Source → Sink	U	V	W	FR
1	Phase V → Phase W	Н	Н	L	Н
	Phase W → Phase V				L
0	Phase U → Phase W	Н	L	L	Н
2	Phase W → Phase U				L
3	Phase $U \rightarrow Phase V$	Н	L	Н	Н
	Phase V → Phase U				L
4	Phase W → Phase V	L	L	Н	Н
	Phase V → Phase W				L
5	Phase W → Phase U		Н	Н	Н
	Phase U → Phase W	L			L
6	Phase V → Phase U			L	Н
	Phase U → Phase V	L	Н		L

Note: In the FR column, "H" refers to a voltage of 2.75V or higher, and "L" refers to 2.25V or lower (when VCC=5V.)

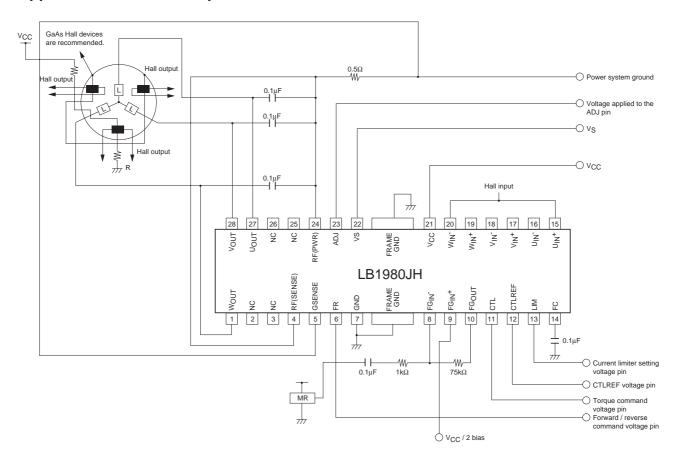
Note: In the Hall input column, "H" refers to the state in the corresponding phase where the +input is at a potential at least 0.01V higher than the -input, and "L" refers to the state where the -input is at a potential at least 0.01V higher than the +input.

Note: Since the drive technique adopted is a  $180^{\circ}$  technique, phases other than the sink and source phase do not turn off.

#### **Control Function and Current Limiter Function**



## **Application Circuit Example**



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